



## PNP HIGH VOLTAGE TRANSISTOR

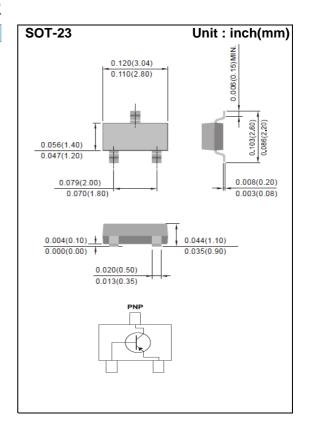
VOLTAGE 300 Volt POWER 250 mWatt

#### **FEATURES**

- PNP silicon, planar design
- High voltage (max. 300V)
- Lead free in compliance with EU RoHS 2.0
- · Green molding compound as per IEC 61249 standard

#### **MECHANICAL DATA**

- · Case: SOT-23, Plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- · Marking: A92



#### **ABSOLUTE RATINGS**

PARAMETER	CONDITIONS	SYMBOL	MIN.	MAX.	UNIT
Collector-base voltage	open emitter	Vсво	-300	-	V
Collector-emitter voltage	open base	VCEO	-300	-	V
Emitter-base voltage	open collector	VEBO	-5	-	V
Collector current (DC)		Ic	-	-500	mA
Peak collector current		Ісм	-	-600	mA
Peak base current		Iвм	-	-100	mA
Total power dissipation	T <sub>AMB</sub> <25°C; note1	Ртот	-	250	mW
Storage temperature		Тѕтѕ	-55	+150	°C
Junction temperature		TJ	-55	+150	۰C
Operating ambient temperature		Тамв	-55	+150	°C

Note 1: Mounted on FR4 PCB at 1 inch square copper pad.





#### THERMAL CHARACTERISTICS

PARAMETER	CONDITIONS	SYMBOL	VALUE	UNIT
Typical Thermal resistance from junction to ambient	note 1	Rоја	500	°C/W

Note 1: Mounted on FR4 PCB at 1 inch square copper pad.

CHARACTERISTICS T<sub>AMB</sub>=25°C unless otherwise specified

PARAMETER	CONDITIONS	SYMBOL	MIN.	MAX.	UNIT
Collector-emitter breakdown voltage	I c=-1mA;I <sub>B</sub> =0	V <sub>(BR)CEO</sub>	-300	-	V
Collector-base breakdown voltage	I c=-100uA; I <sub>E</sub> =0	V <sub>(BR)CBO</sub>	-300	-	V
Emitter-base breakdown voltage	I E=-100uA; I <sub>C</sub> =0	V <sub>(BR)EBO</sub>	-5	-	V
Collector cut-off current	I E=0; V CB=-200V	I сво	-	-250	nA
Collector-emitter cut-off current	V ces=-300V	I ces	-	-250	nA
Emitter cut-off current	I C=0; VEB=-3V	I EBO	-	-100	nA
DC current gain	VcE=-10V;note 2 I c=-1mA I c=-10mA I c=-30mA	hfe	25 40 25	- - -	-
Collector-emitter saturation voltage	I c=-20mA; I B=-2mA	V CE(SAT)	-	-500	mV
Base-emitter saturation voltage	I c=-20mA; I B=-2mA	VBE(SAT)	-	-900	mV
Collector capacitance	I E=0; VCB=-20V; f=1MHz	Cc	-	6	pF
Transition frequency	I c=-10mA; Vc=-20V; f=100MHz	fτ	50	-	MHz

Note 2: Pulse test : tp < 300μs;δ<0.02





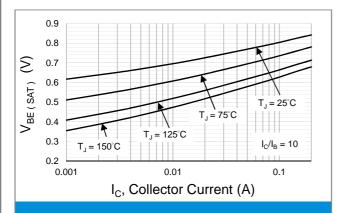


Fig.1 Typical Base-Emitter Saturation Voltage

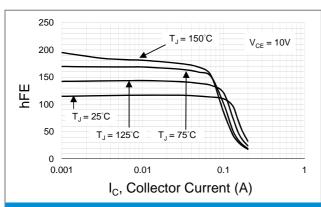


Fig.3 Typical DC Current Gain vs Collector Current

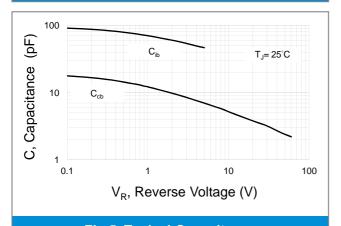


Fig.5 Typical Capacitance

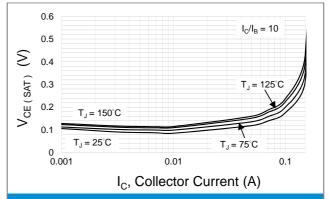


Fig.2 Typical Collector-Emitter Saturation Voltage

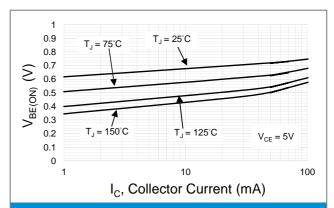
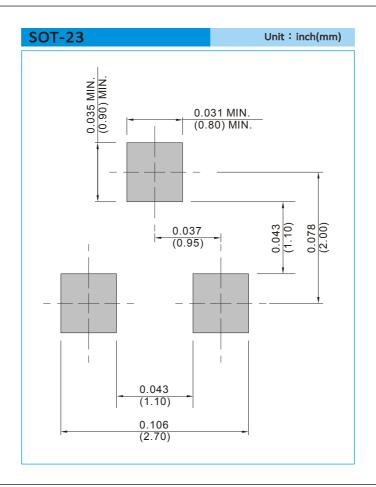


Fig.4 Typical Base - Emitter Voltage vs Collector Current





#### **MOUNTING PAD LAYOUT**



### **ORDER INFORMATION**

• Packing information

T/R - 12K per 13" plastic Reel

T/R - 3K per 7" plastic Reel

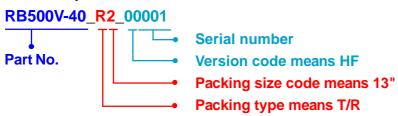




## Part No\_packing code\_Version

MMBTA92\_R1\_00001 MMBTA92\_R2\_00001

## For example:



Packing Code XX			Version Code XXXXX			
Packing type	1 <sup>st</sup> Code	Packing size code	2 <sup>nd</sup> Code	HF or RoHS	1 <sup>st</sup> Code	2 <sup>nd</sup> ~5 <sup>th</sup> Code
Tape and Ammunition Box (T/B)	Α	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	В	13"	2			
Tube Packing (T/P)	Т	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			





## **Disclaimer**

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties
  of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation.
   Customers are responsible in comprehending the suitable use in particular applications.
   Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Panjit manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H BC546/116 BC557/116 BSW67A NTE187A NTE195A NTE2302 NTE2330 NTE63 C4460 2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA2126-E 2SB1204S-TL-E 2SC5488A-TL-H 2SD2150T100R SP000011176 FMMTA92QTA 2N2369ADCSM 2SC2412KT146S 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E US6T6TR 732314D CMXT3906 TR CPH3121-TL-E CPH6021-TL-H 873787E UMX21NTR EMT2T2R MCH6102-TL-E FP204-TL-E NJL0302DG 2N3583 2SA1434-TB-E 2SC3143-4-TB-E 2SD1621S-TD-E 30A02MH-TL-E NSV40301MZ4T1G NTE13 NTE15 NTE16001 NTE16006 NTE26 NTE320